Monolithic Digital IC

SANYO

NO.1831C

LB1205

High-Voltage, High-Current Darlington Driver

Functions and Features

- . 4-unit, high-voltage (65V), high-current (1.5A) Darlington driver
- . PNP input type (Low active)
- . On-chip spark killer diodes
- . On-chip input protection diodes
- . Capable of being driven directly from 5V-operated CMOS, TTL

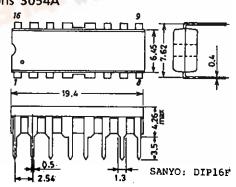
Absolute Maximum Ratings at Ta=25°C	·	unit
Maximum Supply Voltage V _{DD} max	7.0	v
V _{CC} max	62	V
Output Supply Voltage Vomax	65	V
Input Supply Voltage V _{IN} max V _{IN} ≧Gnd	$V_{\rm DD} = 7.0 \text{ to } V_{\rm DD} + 10.0$	a G V
Output Current I max	1.5	A
Spark Killer Diode Forward IFs Current	1.5	A
Allowable Power Dissipation Pdmax*	*1.9	W
Operating Temperature Topr	-20 to +75	°C
Storage Temperature Tstg	-55 to +150	°C
Mounted on the recommended printed	circuit board 2.6	W

Allowable Operating Condition	s at Ta	=25 ⁰ C	uı	nit
Supply Voltage Range	$v_{ m DD}$		3.0 to 7.0	
Input "ON" Level Voltage	VINon	V _{TN} ≧Gnd, Io=1.0A	V _{DD} -7.0 to V _{DD} -2.6	V
Input "OFF" Level Voltage	VINCEE		V _{DD} -0.3 to V _{DD} +10.0	

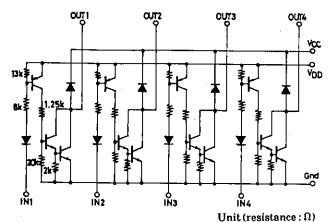
Ta=25°C Vosat1 Vosat2 Vosat3 Vosus IIN VFs	V _{IN} =V _{DD} =5.0V V _{IN} =V _{DD} -5.0V, Io=0.5A , Io=1.0A , Io=1.5A Io=100mA V _{DD} =7.0V, V _{IN} =V _{DD} -7.0V I _{Fs} =1.5A	min	tур	max 1.2 1.5 2.0 1.0 3.0	unit V V V V mA V
I_{Rs}	V _{CC} =62V, Vo=0V			30	μA
	Vosat1 Vosat2 Vosat3 Vosus IIN VFs	Vosat2 " ,Io=1.0A Vosat3 " ,Io=1.5A Vosus Io=100mA V _{DD} =7.0V,V _{IN} =V _{DD} -7.0V V _{FS} I _{FS} =1.5A	Vosat1 Vosat2 Vosat2 Vosat3 Vosus Io=100mA Vosus Io=100mA VDD=7.0V,VIN=VDD-7.0V VFs IFs=1.5A	Vosat1 Vosat2 Vosat2 Vosat3 Vosus Io=100mA Vosus Io=100mA VDD=7.0V, VIN=VDD-7.0V VFs IFs=1.5A	Vosat1 VIN=VDD-5.0V, Io=0.5A 1.2 Vosat2

Package Dimensions 3054A

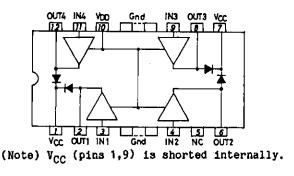
(unit: mm)

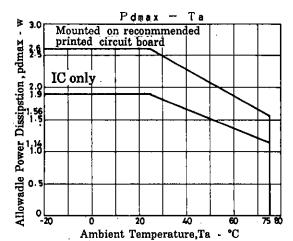


Equivalent Circuit

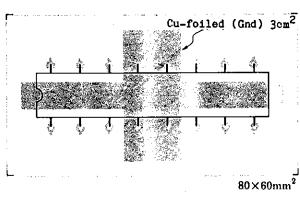


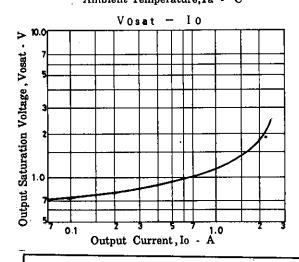
Pin Assignment





Recommended Printed Circuit Pattern





- No products described or contained herein are intended for use in surgical implants, life-support systems, aerospace equipment, nuclear power control systems, vehicles, disaster/crime-prevention equipment and the like, the failure of which may directly or indirectly cause injury, death or property loss.
- Anyone purchasing any products described or contained herein for an above-mentioned use shall:
 - ① Accept full responsibility and indemnify and defend SANYO ELECTRIC Co., LTD., its affiliates, subsidiaries and distributors and all their officers and employees, jointly and severally, against any and all claims and litigation and all damages, cost and expenses associated with such use:
 - 2 Not impose any responsibility for any fault or negligence which may be cited in any such claim or litigation on SANYO ELECTRIC CO., LTD., its affiliates, subsidiaries and distributors or any of their officers and employees jointly or severally.
- Information '(including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.